## Features

－ 35 mm creepage／clearance
■ Compact 4－pin surface mount package （ 2.4 mm maximum standoff height）
■ Current Transfer Ratio in selected groups DC Input：
FODM121：50－600\％
FODM121A：100－300\％
FODM121B：50－150\％
FODM2701：50－300\％
FODM2701A：150－300\％ FODM2701B：80－160\％
FODM121C：100－200\％FODM124：100\％MIN
FODM121D：50－100\％
FODM121E：150－300\％
FODM121F：100－600\％
FODM121G：200－400\％
AC Input：
FODM2705：50－300\％
－Available in tape and reel quantities of 2500
－Applicable to Infrared Ray reflow（ $260^{\circ} \mathrm{C}$ max， 10 sec ．）
■ C－UL，UL and VDE＊certifications
＊option＇V＇required

## Applications

－Digital logic inputs
■ Microprocessor inputs
■ Power supply monitor
■ Twisted pair line receiver
－Telephone line receiver

## Description

The FODM124，FODM121，and FODM2701 series consists of a gallium arsenide infrared emitting diode driving a phototransistor in a compact 4－pin mini－flat package．The lead pitch is 2.54 mm ．The FODM2705 consists of two gallium arsenide infrared emitting diodes connected in inverse parallel for AC operation．

Package Dimensions



Note：
All dimensions are in millimeters．
 FODM121，FODM124，FODM2701


Equivalent Circuit FODM2705

Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise specified)
Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

| Symbol | Parameter | Value | Units |
| :---: | :---: | :---: | :---: |

TOTAL PACKAGE

| $\mathrm{T}_{\text {STG }}$ | Storage Temperature | -40 to +125 | ${ }^{\circ} \mathrm{C}$ |
| :---: | :--- | :---: | :---: |
| $\mathrm{T}_{\mathrm{OPR}}$ | Operating Temperature | -40 to +100 | ${ }^{\circ} \mathrm{C}$ |
| EMITTER |  |  |  |
| $\mathrm{I}_{\mathrm{F}(\text { avg })}$ | Continuous Forward Current | 50 | mA |
| $\mathrm{I}_{\mathrm{F}(\mathrm{pk})}$ | Peak Forward Current (1 $1 \mu \mathrm{~s}$ pulse, 300 pps.$)$ | 1 | A |
| $\mathrm{~V}_{\mathrm{R}}$ | Reverse Input Voltage | 6 | V |
| $\mathrm{P}_{\mathrm{D}}$ | Power Dissipation <br> Derate linearly (above $\left.25^{\circ} \mathrm{C}\right)$ | 70 | mW |
|  |  | 0.65 | $\mathrm{~mW} /{ }^{\circ} \mathrm{C}$ |

## DETECTOR

|  | Continuous Collector Current |  | 80 | mA |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{P}_{\mathrm{D}}$ | Power Dissipation <br> Derate linearly (above $25^{\circ} \mathrm{C}$ ) |  | 150 | mW |
|  |  |  | 2.0 | $\mathrm{mW} /{ }^{\circ} \mathrm{C}$ |
| $\mathrm{V}_{\text {CEO }}$ | Collector-Emitter Voltage | FODM2701 Series, FODM2705 | 40 | V |
|  |  | FODM121 Series, FODM124 | 80 |  |
| $\mathrm{V}_{\mathrm{ECO}}$ | Emitter-Collector Voltage |  | 7 | V |

Electrical Characteristics ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ )
Individual Component Characteristics

| Symbol | Parameter | Test Conditions | Device | Min. | Typ.* | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| EMITTER |  |  |  |  |  |  |  |
| $V_{F}$ | Forward Voltage | $\mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}$ | FODM121 Series, FODM124 | 1.0 |  | 1.3 | V |
|  |  | $\mathrm{I}_{\mathrm{F}}=5 \mathrm{~mA}$ | FODM2701 Series |  |  | 1.4 |  |
|  |  | $\mathrm{I}_{\mathrm{F}}= \pm 5 \mathrm{~mA}$ | FODM2705 |  |  |  |  |
| $\mathrm{I}_{\mathrm{R}}$ | Reverse Current | $\mathrm{V}_{\mathrm{R}}=5 \mathrm{~V}$ | FODM2701 Series |  |  | 5 | $\mu \mathrm{A}$ |
|  |  |  | FODM121 Series |  |  |  |  |
|  |  |  | FODM124 |  |  |  |  |
| DETECTOR |  |  |  |  |  |  |  |
| $\mathrm{BV}_{\text {CEO }}$ | Breakdown Voltage Collector to Emitter | $\mathrm{I}_{\mathrm{C}}=1 \mathrm{~mA}, \mathrm{I}_{\mathrm{F}}=0$ | FODM121 Series, FODM124 | 80 |  |  | V |
|  |  |  | FODM2701 Series, FODM2705 | 40 |  |  |  |
| $\mathrm{BV}_{\text {ECO }}$ | Emitter to Collector | $\mathrm{I}_{\mathrm{E}}=100 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{F}}=0$ | All | 7 |  | - | V |
| $\mathrm{I}_{\text {CEO }}$ | Collector Dark Current | $\mathrm{V}_{\mathrm{CE}}=40 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=0$ | All |  |  | 100 | nA |
| $\mathrm{C}_{\text {CE }}$ | Capacitance | $\mathrm{V}_{\mathrm{CE}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ | All |  | 10 |  | pF |

Electrical Characteristics (Continued) ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ )
Transfer Characteristics

| Symbol | Characteristic | Test Conditions | Device | Min. | Typ.* | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CTR | DC Current Transfer Ratio | $\mathrm{I}_{\mathrm{F}}= \pm 5 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V}$ | FODM2705 | 50 |  | 300 | \% |
|  |  | $\mathrm{I}_{\mathrm{F}}=5 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V}$ | FODM2701 | 50 |  | 300 |  |
|  |  |  | FODM2701A | 150 |  | 300 |  |
|  |  |  | FODM2701B | 80 |  | 160 |  |
|  |  | $\mathrm{I}_{\mathrm{F}}=5 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V}$ | FODM121 | 50 |  | 600 |  |
|  |  |  | FODM121A | 100 |  | 300 |  |
|  |  |  | FODM121B | 50 |  | 150 |  |
|  |  |  | FODM121C | 100 |  | 200 |  |
|  |  |  | FODM121D | 50 |  | 100 |  |
|  |  |  | FODM121E | 150 |  | 300 |  |
|  |  |  | FODM121F | 100 |  | 600 |  |
|  |  |  | FODM121G | 200 |  | 400 |  |
|  |  | $\mathrm{I}_{\mathrm{F}}=1 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=0.4 \mathrm{~V}$ | FODM121F | 30 |  |  |  |
|  |  | $\mathrm{I}_{\mathrm{F}}=1 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=0.5 \mathrm{~V}$ | FODM124 | 100 |  | 1200 |  |
|  |  | $\mathrm{I}_{\mathrm{F}}=0.5 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=1.5 \mathrm{~V}$ | FODM124 | 50 |  |  |  |
|  | CTR Symmetry | $\mathrm{I}_{\mathrm{F}}= \pm 5 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V}$ | FODM2705 | 0.3 |  | 3.0 |  |
| $\mathrm{V}_{\mathrm{CE} \text { (SAT) }}$ | Saturation Voltage | $\mathrm{I}_{\mathrm{F}}= \pm 10 \mathrm{~mA}, \mathrm{I}_{\mathrm{C}}=2 \mathrm{~mA}$ | FODM2705 |  |  | 0.3 | V |
|  |  | $\mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}, \mathrm{I}_{\mathrm{C}}=2 \mathrm{~mA}$ | $\begin{aligned} & \text { FODM2701 } \\ & \text { Series } \end{aligned}$ |  |  | 0.3 |  |
|  |  | $\mathrm{I}_{\mathrm{F}}=8 \mathrm{~mA}, \mathrm{I}_{\mathrm{C}}=2.4 \mathrm{~mA}$ | $\begin{gathered} \hline \text { FODM121 } \\ \text { Series } \end{gathered}$ |  |  | 0.4 |  |
|  |  | $\mathrm{I}_{\mathrm{F}}=1 \mathrm{~mA}, \mathrm{I}_{\mathrm{C}}=0.5 \mathrm{~mA}$ | FODM124 |  |  | 0.4 |  |
| $\mathrm{t}_{\mathrm{r}}$ | Rise Time (Non-Saturated) | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=2 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V}, \\ & \mathrm{R}_{\mathrm{L}}=100 \Omega \end{aligned}$ | All |  | 3 |  | $\mu \mathrm{s}$ |
| $t_{f}$ | Fall Time (Non-Saturated) | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=2 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=5 \mathrm{~V}, \\ & \mathrm{R}_{\mathrm{L}}=100 \Omega \end{aligned}$ | All |  | 3 |  | $\mu \mathrm{s}$ |

Isolation Characteristics

| Characteristic | Test Conditions | Symbol | Device | Min. | Typ.* | Max. | Unit |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Steady State Isolation Voltage ${ }^{(1)}$ | 1 Minute | $\mathrm{V}_{\text {ISO }}$ | All | 3750 |  |  | VRMS |

${ }^{*}$ All typicals at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$
Note:

1. Steady state isolation voltage, $\mathrm{V}_{\text {ISO }}$, is an internal device dielectric breakdown rating. For this test, pins 1 and 2 are common, and pins 3 and 4 are common.

## Typical Performance Curves

Fig. 1 Forward Current vs. Forward Voltage


Fig. 3 Current Transfer Ratio vs. Forward Current (FODM121/2701/2705)


Fig. 5 Collector Current vs. Ambient Temperature (FODM121/2701/2705)


Fig. 2 Collector-Emitter Saturation Voltage vs. Ambient Temperature (FODM121/2701/2705)


Fig. 4 Collector Current vs. Forward Current (FODM121/2701/2705)


Fig. 6 Collector Current vs. Collector-Emitter Voltage (FODM121/2701/2705)


Fig 7. Collector Dark Current vs. Ambient
Temperature (FODM121/2701/2705)


Fig. 9 Switching Time vs. Load Resistance (FODM121/2701/2705)


Fig. 11 Current Transfer Ratio vs.
Forward Current (FODM124)


Fig. 8 Normalized Current Transfer Ratio vs. Ambient Temperature (FODM121/2701/2705)


Fig. 10 Collector-Emitter Saturation Voltage vs. Ambient Temperature (FODM124)


Fig 12. Collector Current vs. Forward Current
(FODM124)


Fig 13. Collector Current vs. Ambient Temperature (FODM124)


Fig. 15 Collector Dark Current vs. Ambient Temperature (FODM124)


Fig. 14 Collector Current vs. Collector-Emitter Voltage (FODM124)


Fig. 16 Normalized Current Transfer Ratio vs. Ambient Temperature (FODM124)


Fig. 17 Switching Time vs. Load Resistance (FODM124)


## Ordering Information

| Option | Description |
| :---: | :---: |
| V | VDE Approved |
| R2 | Tape and Reel (2500 units) |
| R2V | Tape and Reel (2500 units) and VDE Approved |

## Marking Information



## Carrier Tape Specifications



|  |  | 2.54 Pitch |
| :---: | :---: | :---: |
| Description | Symbol | Dimensions |
| Tape Width | W | $12.00 \pm 0.4$ |
| Tape Thickness | t | $0.35 \pm 0.02$ |
| Sprocket Hole Pitch | $\mathrm{P}_{0}$ | $4.00 \pm 0.20$ |
| Sprocket Hole Dia. | $\mathrm{D}_{0}$ | $1.55 \pm 0.20$ |
| Sprocket Hole Location | E | $1.75 \pm 0.20$ |
| Pocket Location | F | $5.50 \pm 0.20$ |
|  | $\mathrm{P}_{2}$ | $2.00 \pm 0.20$ |
| Pocket Pitch | P | $8.00 \pm 0.20$ |
| Pocket Dimension | $\mathrm{A}_{0}$ | $4.75 \pm 0.20$ |
|  | $\mathrm{B}_{0}$ | $7.30 \pm 0.20$ |
|  | $\mathrm{K}_{0}$ | $2.30 \pm 0.20$ |
| Pocket Hole Dia. | $\mathrm{D}_{1}$ | $1.55 \pm 0.20$ |
| Cover Tape Width | $\mathrm{W}_{1}$ | 9.20 |
| Cover Tape Thickness | d | $0.065 \pm 0.02$ |
| Max. Component Rotation or Tilt |  | $20^{\circ}$ max |
| Devices Per Reel |  | 2500 |
| Reel Diameter |  | 330 mm (13") |

## Footprint Drawing for PCB Layout



## Note:

All dimensions are in mm.

## Reflow Profile



| Profile Freature | Pb-Free Assembly Profile |
| :--- | :---: |
| Temperature Min. (Tsmin) | $150^{\circ} \mathrm{C}$ |
| Temperature Max. (Tsmax) | $200^{\circ} \mathrm{C}$ |
| Time ( $\mathrm{t}_{\mathrm{S}}$ ) from (Tsmin to Tsmax) | $60-120$ seconds |
| Ramp-up Rate ( $\mathrm{t}_{\mathrm{L}}$ to $\mathrm{t}_{\mathrm{P}}$ ) | $3^{\circ} \mathrm{C} /$ second max. |
| Liquidous Temperature $\left(\mathrm{T}_{\mathrm{L}}\right)$ | $217^{\circ} \mathrm{C}$ |
| Time ( $\mathrm{t}_{\mathrm{L}}$ ) Maintained Above ( $\mathrm{T}_{\mathrm{L}}$ ) | $60-150$ seconds |
| Peak Body Package Temperature | $260^{\circ} \mathrm{C}+0^{\circ} \mathrm{C} /-5^{\circ} \mathrm{C}$ |
| Time ( $\left.\mathrm{t}_{\mathrm{P}}\right)$ within $5^{\circ} \mathrm{C}$ of $260^{\circ} \mathrm{C}$ | 30 seconds |
| Ramp-down Rate $\left(\mathrm{T}_{\mathrm{P}}\right.$ to $\left.\mathrm{T}_{\mathrm{L}}\right)$ | $6^{\circ} \mathrm{C} /$ second max. |
| Time $25^{\circ} \mathrm{C}$ to Peak Temperature | 8 minutes max. |

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| EcoSPARK ${ }^{\text {® }}$ | IntelliMAX ${ }^{\text {TM }}$ | $\bigcirc$ | TinyPower ${ }^{\text {TM }}$ |
| EfficentMax ${ }^{\text {TM }}$ | ISOPLANAR ${ }^{\text {TM }}$ | тм | TinyPWM ${ }^{\text {TM }}$ |
| EZSWITCH ${ }^{\text {m }}$ * | MegaBuck ${ }^{\text {TM }}$ | Saving our world, $1 \mathrm{~mW} / \mathrm{W} / \mathrm{kW}$ at a time ${ }^{\text {TM }}$ | TinyWire ${ }^{\text {TM }}$ |
| $\mathrm{EF}^{\text {m* }}$ | MICROCOUPLER ${ }^{\text {TM }}$ | SmartMax ${ }^{\text {TM }}$ | TriFault Detect ${ }^{\text {TM }}$ |
| E\% | MicroFET ${ }^{\text {TM }}$ | SMART START ${ }^{\text {TM }}$ | TRUECURRENT ${ }^{\text {TM* }}$ |
| $5^{\circledR}$ | MicroPak ${ }^{\text {TM }}$ | SPM ${ }^{\text {® }}$ | $\mu$ SerDes ${ }^{\text {TM }}$ |
|  | MillerDrive ${ }^{\text {TM }}$ | STEALTH ${ }^{\text {TM }}$ |  |
| Fairchild ${ }^{\text {® }}$ | MotionMax ${ }^{\text {TM }}$ | SuperFET ${ }^{\text {TM }}$ | WerDes |
| Fairchild Semiconductor ${ }^{\text {® }}$ | Motion-SPM ${ }^{\text {TM }}$ | SuperSOT ${ }^{\text {Tm-3 }}$ | SerDes ${ }^{\text {- }}$ |
| FACT Quiet Series ${ }^{\text {TM }}$ | OPTOLOGIC ${ }^{\text {® }}$ | SuperSOT ${ }^{\text {TM }}$-6 |  |
| $\mathrm{FACT}^{\circledR}$ | OPTOPLANAR ${ }^{\text {® }}$ | SuperSOT ${ }^{\text {Tм }}$-8 | Ultra FRFET ${ }^{\text {TM }}$ |
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